

# Silicon SPDT Switch, Nonreflective, 9 kHz to 45 GHz

#### **FEATURES**

- ▶ Ultra-wideband frequency range: 9 kHz to 45 GHz
- ▶ Nonreflective design
- Low insertion loss
  - ▶ 0.9 dB typical to 18 GHz
  - ▶ 1.6 dB typical to 40 GHz
  - ▶ 1.7 dB typical to 45 GHz
- ▶ High Isolation: 42 dB typical to 45 GHz
- ▶ High input linearity
  - ▶ 0.1 dB power compression (P0.1dB): 31 dBm
  - ▶ Third-order intercept (IP3): 53 dBm
- ► High power handling at T<sub>CASE</sub> = 85°C
  - ▶ 30 dBm through path
  - 24 dBm terminated path
  - ▶ 30 dBm hot switching (RFC port)
- ▶ RF settling time (0.1 dB final RF output): 3.5 µs
- ▶ No low-frequency spurious signals
- ▶ All off state control
- ▶ Positive Control Interface: CMOS-/LVTTL-compatible
- ▶ 20-lead, 3.0 mm × 3.0 mm LGA package

#### **APPLICATIONS**

- ▶ Test and instrumentation
- ▶ Cellular Infrastructure: 5G millimeter wave
- ▶ Military radios, radars, and electronic countermeasures (ECMs)
- Microwave radios and very small aperture terminals (VSATs)
- Industrial scanner

#### **FUNCTIONAL BLOCK DIAGRAM**

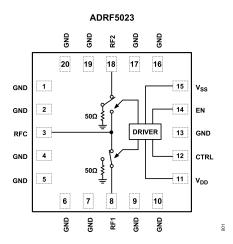


Figure 1. Functional Block Diagram

#### **GENERAL DESCRIPTION**

The ADRF5023 is a nonreflective, single-pole double-throw (SPDT) switch manufactured in the silicon process.

The ADRF5023 operates from 9 kHz to 45 GHz with a typical insertion loss of 1.7 dB and isolation of 42 dB. The device has a RF input power handling capability of 30 dBm for the through path, 24 dBm for the terminated path, and 30 dBm for the hot switching at the RF common port.

The ADRF5023 requires a positive supply of 3.3 V and a negative supply of –3.3 V. The device employs complementary metal-oxide semiconductor (CMOS)-/low voltage transistor to transistor logic (LVTTL)-compatible controls.

The ADRF5023 can also operate with a single positive supply voltage ( $V_{DD}$ ) applied while the negative supply voltage ( $V_{SS}$ ) is tied to ground. In this operating condition, the small signal performance is maintained while the switching characteristics, linearity, and power handling performance is derated. See Table 2 for more details.

The ADRF5023 is pin-compatible with the ADRF5022, a fast switching version that operates from 100 MHz to 45 GHz.

The ADRF5023 comes in a 20-lead, 3.0 mm × 3.0 mm, RoHS-compliant, land grid array (LGA) package and can operate from −40°C to +105°C.

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|---|-------------------------------------|--------------------------------------|
| REVISION HISTORY  |                                     |                                      |
| 10/2023—Rev. 0 to Rev. A Changes to General Description Section Changes to Table 2 Changes to Table 3   |                                     | 4                                    |
| Changes to Ordering Guide   | 1                                   | 2                                    |

1/2023—Revision 0: Initial Version

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# **SPECIFICATIONS**

 $V_{DD} = 3.3 \text{ V}, V_{SS} = -3.3 \text{ V}, \text{CTRL voltage ($V_{CTRL}$)/EN voltage ($V_{EN}$)} = 0 \text{ V or V}_{DD}, \text{ and T}_{CASE} = 25^{\circ}\text{C}, 50 \text{ }\Omega \text{ system, unless otherwise noted.}$ 

Table 1. Electrical Specifications

| Parameter                           | Symbol                                | Test Conditions/Comments                                    | Min Typ  | Max    | Unit     |
|-------------------------------------|---------------------------------------|---|----------|--------|----------|
| FREQUENCY RANGE                     | f                                     |   | 0.009    | 45,000 | MHz      |
| INSERTION LOSS                      |                                       |   |          |        |          |
| Between RFC and RF1/RF2 (On)        |                                       | 9 kHz to 18 GHz   | 0.9      |        | dB       |
| , ,                                 |                                       | 18 GHz to 26 GHz  | 1.1      |        | dB       |
|                                     |                                       | 26 GHz to 35 GHz  | 1.4      |        | dB       |
|                                     |                                       | 35 GHz to 40 GHz  | 1.6      |        | dB       |
|                                     |                                       | 40 GHz to 45 GHz  | 1.7      |        | dB       |
| RETURN LOSS                         |                                       |   |          |        |          |
| RFC and RF1/RF2 (On)                |                                       | 9 kHz to 18 GHz   | 20       |        | dB       |
|                                     |                                       | 18 GHz to 26 GHz  | 20       |        | dB       |
|                                     |                                       | 26 GHz to 35 GHz  | 18       |        | dB       |
|                                     |                                       | 35 GHz to 40 GHz  | 18       |        | dB       |
|                                     |                                       | 40 GHz to 45 GHz  | 18       |        | dB       |
| RF1/RF2 (Off)                       |                                       | 9 kHz to 18 GHz   | 21       |        | dB       |
| 14 1/14 2 (OII)                     |                                       | 18 GHz to 26 GHz  | 21       |        | dB       |
|                                     |                                       | 26 GHz to 35 GHz  | 16       |        | dB       |
|                                     |                                       | 35 GHz to 40 GHz  | 13       |        | dB       |
|                                     |                                       | 40 GHz to 45 GHz  | 12       |        | dB       |
| SOLATION                            |                                       | 40 OF 12 TO 40 OF 12  | 12       |        | UD UD    |
| Between RFC and RF1/RF2 (Off)       |                                       | 9 kHz to 18 GHz   | 55       |        | dB       |
| Detweet I'vi O and Ivi I/vi 2 (Oil) |                                       | 18 GHz to 26 GHz  | 55       |        | dB       |
|                                     |                                       | 26 GHz to 35 GHz  | 55       |        | dB       |
|                                     |                                       | 35 GHz to 40 GHz  | 50       |        | dB       |
|                                     |                                       | 40 GHz to 45 GHz  | 49       |        | dB       |
| Between RF1 and RF2                 |                                       | 9 kHz to 18 GHz   | 60       |        | dB       |
| Detween NET and NEZ                 |                                       | 18 GHz to 26 GHz  | 56       |        |          |
|                                     |                                       |   |          |        | dB       |
|                                     |                                       | 26 GHz to 35 GHz  | 48       |        | dB       |
|                                     |                                       | 35 GHz to 40 GHz<br>40 GHz to 45 GHz                        | 44<br>42 |        | dB<br>dB |
| SWITCHING CHARACTERISTICS           |                                       | 40 GHZ 10 43 GHZ  | 42       |        | UD       |
| Rise and Fall Time                  |                                       | 100/ to 000/ of DE output                                   | 0.5      |        |          |
|                                     | t <sub>RISE</sub> , t <sub>FALL</sub> | 10% to 90% of RF output                                     | 0.5      |        | μs       |
| On and Off Time                     | $t_{ON}, t_{OFF}$                     | 50% V <sub>CTRL</sub> to 90% of RF output                   | 1.8      |        | μs       |
| 0.1 dB RF Settling Time             |                                       | 50% V <sub>CTRL</sub> to 0.1 dB of final RF output          | 3.5      |        | μs       |
| NPUT LINEARITY <sup>1</sup>         | D0.4 dD                               | f = 1 MHz to 40 GHz   | 0.4      |        | -ID      |
| 0.1 dB Power Compression            | P0.1dB                                | T   | 31       |        | dBm      |
| Input Third-Order Intercept         | IIP3                                  | Two-tone input power = 14 dBm each tone, $\Delta f$ = 1 MHz | 53       |        | dBm      |
| SUPPLY CURRENT                      |                                       | V <sub>DD</sub> , V <sub>SS</sub> pins                      |          |        |          |
| Positive Supply Current             | I <sub>DD</sub>                       | יחח. 29. יחח.   | 150      |        | μA       |
| Negative Supply Current             | I <sub>SS</sub>                       |   | 520      |        | μA       |
| DIGITAL CONTROL INPUTS              | '55                                   |   | 020      |        | h, ,     |
| Voltage                             |                                       |   |          |        |          |
| Low                                 | V.,                                   |   | 0        | 0.8    | V        |
|                                     | V <sub>INL</sub>                      |   | 1.2      | 3.3    | V        |
| High                                | $V_{INH}$                             |   | 1.2      | ა.ა    | V        |
| Current                             |                                       |   | _ 4      |        |          |
| Low                                 | I <sub>INL</sub>                      | CTDI  | <1       |        | μA       |
| High                                | I <sub>INH</sub>                      | CTRL  | < 1      |        | μA       |

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## **SPECIFICATIONS**

Table 1. Electrical Specifications (Continued)

| Parameter                       | Symbol            | Test Conditions/Comments  | Min   | Тур | Max      | Unit |
|---------------------------------|-------------------|---|-------|-----|----------|------|
|                                 |                   | EN  |       | 33  |          | μA   |
| RECOMMENDED OPERATING CONDITONS |                   |   |       |     |          |      |
| Positive Supply Voltage         | $V_{DD}$          |   | 3.15  |     | 3.45     | ٧    |
| Negative Supply Voltage         | V <sub>SS</sub>   |   | -3.45 |     | -3.15    | V    |
| Digital Control Input Voltage   | V <sub>CTRL</sub> |   | 0     |     | $V_{DD}$ | V    |
| RF Input Power <sup>2, 3</sup>  | P <sub>IN</sub>   | f = 1 MHz to 40 GHz, T <sub>CASE</sub> = 85°C                   |       |     |          |      |
| Through Path                    |                   | RF signal is applied to the RFC or through connected RF1/RF2    |       |     | 30       | dBm  |
| Terminated Path                 |                   | RF signal is applied to terminated RF1/RF2                      |       |     | 24       | dBm  |
| Hot Switching                   |                   | RF signal is applied to the RFC while switching between RF1/RF2 |       |     | 30       | dBm  |
| Case Temperature                | T <sub>CASE</sub> |   | -40   |     | +105     | °C   |

<sup>&</sup>lt;sup>1</sup> For input linearity performance over frequency, see Figure 14 to Figure 17.

## **SINGLE-SUPPLY OPERATION**

 $V_{DD}$  = 3.3 V,  $V_{SS}$  = 0 V,  $V_{CTRL}/V_{EN}$  = 0 V or  $V_{DD}$  V,  $T_{CASE}$  = 25°C, 50  $\Omega$  system, unless otherwise noted.

Table 2. Single-Supply Operational Specifications

| Parameter                       | Symbol                                | Test Conditions/Comments  | Min   | Тур | Max    | Unit |
|---------------------------------|---------------------------------------|---|-------|-----|--------|------|
| FREQUENCY RANGE                 | f                                     |   | 0.009 |     | 45,000 | MHz  |
| SWITCHING CHARACTERISTICS       |                                       |   |       |     |        |      |
| Rise and Fall Time              | t <sub>RISE</sub> , t <sub>FALL</sub> | 10% to 90% of RF output   |       | 2.2 |        | μs   |
| On and Off Time                 | t <sub>ON</sub> , t <sub>OFF</sub>    | 50% V <sub>CTRL</sub> to 90% of RF output                       |       | 5.8 |        | μs   |
| 0.1 dB RF Settling Time         |                                       | 50% V <sub>CTRL</sub> to 0.1 dB of final RF output              |       | 7.8 |        | μs   |
| INPUT LINEARITY                 |                                       | f = 1 MHz to 40 GHz   |       |     |        |      |
| 0.1 dB Power Compression        | P0.1dB                                |   |       | 16  |        | dBm  |
| Input Third-Order Intercept     | IIP3                                  | Two-tone input power = 0 dBm each tone, $\Delta f$ = 1 MHz      |       | 43  |        | dBm  |
| RECOMMENDED OPERATING CONDITONS |                                       |   |       |     |        |      |
| RF Input Power <sup>1, 2</sup>  | P <sub>IN</sub>                       | f = 1 MHz to 40 GHz, T <sub>CASE</sub> = 85°C                   |       |     |        |      |
| Through Path                    |                                       | RF signal is applied to the RFC or through connected RF1/RF2    |       |     | 16     | dBm  |
| Terminated Path                 |                                       | RF signal is applied to terminated RF1/RF2                      |       |     | 12     | dBm  |
| Hot Switching                   |                                       | RF signal is applied to the RFC while switching between RF1/RF2 |       |     | 16     | dBm  |

<sup>&</sup>lt;sup>1</sup> For power derating over frequency, see Figure 2 and Figure 3.

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<sup>&</sup>lt;sup>2</sup> For power derating over frequency, see Figure 2 and Figure 3.

 $<sup>^3</sup>$  For 105°C operation, the power handling degrades from the T<sub>CASE</sub> = 85°C specification by 3 dB.

<sup>&</sup>lt;sup>2</sup> For 105°C operation, the power handling degrades from the  $T_{CASE}$  = 85°C specification by 3 dB.

# **ABSOLUTE MAXIMUM RATINGS**

For recommended operating conditions, see Table 1 and Table 2.

Table 3. Absolute Maximum Ratings

| Parameter  | Rating                                     |
|--|--|
| Supply Voltage   |  |
| Positive   | -0.3 V to +3.6 V                           |
| Negative   | -3.6 V to +0.3 V                           |
| Digital Control Input Voltage  |  |
| Voltage  | $-0.3 \text{ V to V}_{DD} + 0.3 \text{ V}$ |
| Current  | 3 mA                                       |
| RF Input Power, Dual Supply <sup>1</sup> ( $V_{DD}$ = 3.3 V, $V_{SS}$ = -3.3 V, f = 1 MHz to 40 GHz, $T_{CASE}$ = 85°C)                                  |  |
| Through Path   | 31 dBm                                     |
| Terminated Path  | 25 dBm                                     |
| Hot Switching (RFC port)   | 31 dBm                                     |
| RF Input Power, Single Supply <sup>1</sup> ( $V_{DD} = 3.3 \text{ V}$ , $V_{SS} = 0$ V, $f = 1 \text{ MHz}$ to 40 GHz, $T_{CASE} = 85^{\circ}\text{C}$ ) |  |
| Through Path   | 17 dBm                                     |
| Terminated Path  | 13 dBm                                     |
| Hot Switching (RFC port)   | 17 dBm                                     |
| RF Power Under Unbiased Condition  | 17 dBm                                     |
| $(V_{DD}, V_{SS} = 0 V)$   |  |
| Temperature  |  |
| Junction (T <sub>J</sub> )   | 135°C                                      |
| Storage  | -65°C to +150°C                            |
| Reflow   | 260°C                                      |

<sup>&</sup>lt;sup>1</sup> For power derating over frequency, see Figure 2 and Figure 3.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

#### THERMAL RESISTANCE

Thermal performance is directly linked to the printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{JC}$  is the junction to case bottom (channel to package bottom) thermal resistance.

Table 4. Thermal Resistance

| Package Type    | θ <sub>JC</sub> <sup>1</sup> | Unit |
|-----------------|------------------------------|------|
| CC-20-19        |                              |      |
| Through path    | 160                          | °C/W |
| Terminated path | 200                          | °C/W |

 $<sup>^{1}</sup>$   $\theta_{JC}$  was determined by simulation under the following conditions: the heat transfer is due solely to the thermal conduction from the channel through the ground pad to the PCB, and the ground pad is held constant at the operating temperature of 85°C.

#### POWER DERATING CURVES

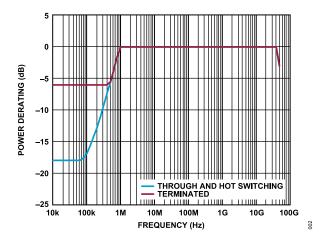


Figure 2. Power Derating vs. Frequency, Low Frequency Detail, T<sub>CASE</sub> = 85°C

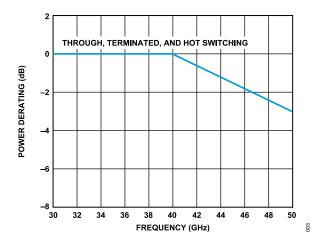


Figure 3. Power Derating vs. Frequency, High Frequency Detail,  $T_{CASE}$  = 85°C

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### **ABSOLUTE MAXIMUM RATINGS**

## **ELECTROSTATIC DISCHARGE (ESD) RATINGS**

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001.

Charged device model (CDM) per ANSI/ESDA/JEDEC JS-002.

# **ESD Ratings for ADRF5023**

Table 5. ADRF5023, 20-Terminal LGA

| ESD Model | Withstand Threshold (V) | Class |
|-----------|-------------------------|-------|
| HBM       | ± 2000 for all pins     | 2     |
| CDM       | ± 500 for all pins      | C2    |

# **ESD CAUTION**



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

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# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

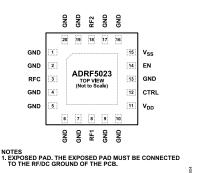


Figure 4. Pin Configuration (Top View)

Table 6. Pin Function Descriptions

| Pin Number                                 | Mnemonic        | Description  |
|--|-----------------|--|
| 1, 2, 4 to 7, 9, 10, 13, 16, 17,<br>19, 20 | GND             | Ground. These pins must be connected to the RF/DC ground of the PCB.   |
| 3  | RFC             | RF Common Port. This pin is DC-coupled to 0 V and AC matched to 50 $\Omega$ . No DC blocking capacitor is required when the RF line potential is equal to 0 V DC.  |
| 8  | RF1             | RF Throw Port 1. This pin is DC-coupled to 0 V and AC matched to 50 $\Omega$ . No DC blocking capacitor is required when the RF line potential is equal to 0 V DC. |
| 11   | $V_{DD}$        | Positive Supply Voltage.   |
| 12   | CTRL            | Control Input Voltage.   |
| 14   | EN              | Enable Input Voltage.  |
| 15   | V <sub>SS</sub> | Negative Supply Voltage.   |
| 18   | RF2             | RF Throw Port 2. This pin is DC-coupled to 0 V and AC matched to 50 $\Omega$ . No DC blocking capacitor is required when the RF line potential is equal to 0 V DC. |
|  | EPAD            | Exposed Pad. The exposed pad must be connected to the RF/DC ground of the PCB.   |

## **INTERFACE SCHEMATICS**



Figure 5. RF Pins (RFC, RF1, RF2) Interface Schematic

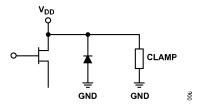


Figure 6.  $V_{DD}$  Pin Interface Schematic

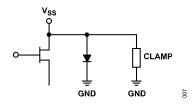


Figure 7. V<sub>SS</sub> Pin Interface Schematic

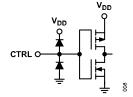


Figure 8. CTRL Pin Interface Schematic

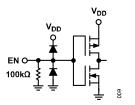


Figure 9. EN Pin Interface Schematic

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### TYPICAL PERFORMANCE CHARACTERISTICS

## **INSERTION LOSS, RETURN LOSS, AND ISOLATION**

 $V_{DD}$  = 3.3 V,  $V_{SS}$  = -3.3 V or 0 V,  $V_{CTRL}/V_{EN}$  = 0 V or  $V_{DD}$ , and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted. Measured on the ADRF5023-EVALZ.

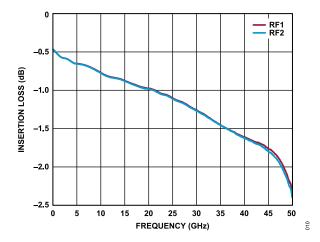


Figure 10. Insertion Loss vs. Frequency at Room Temperature for RF1 and RF2

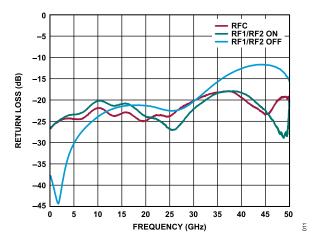


Figure 11. Return Loss vs. Frequency

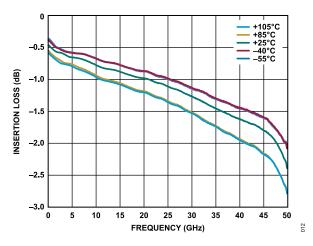


Figure 12. Insertion Loss vs. Frequency over Temperature

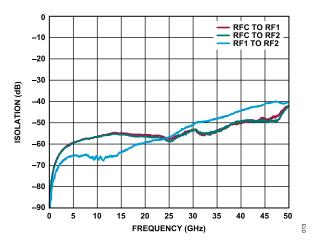


Figure 13. Isolation vs. Frequency

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## TYPICAL PERFORMANCE CHARACTERISTICS

## INPUT POWER COMPRESSION AND THIRD-ORDER INTERCEPT

 $V_{DD}$  = 3.3 V,  $V_{SS}$  = -3.3 V,  $V_{CTRL}/V_{EN}$  = 0 V or  $V_{DD}$ , and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted. The large-signal performance parameters are measured on the ADRF5023-EVALZ.

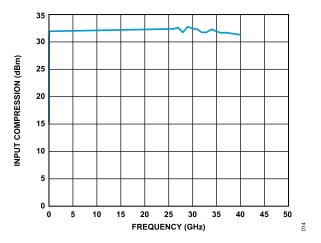


Figure 14. Input 0.1 dB Power Compression vs. Frequency

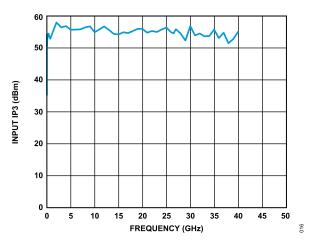


Figure 15. Input IP3 vs. Frequency

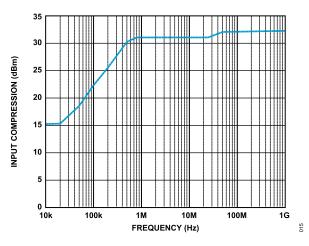


Figure 16. Input 0.1 dB Power Compression vs. Frequency, Low Frequency
Detail

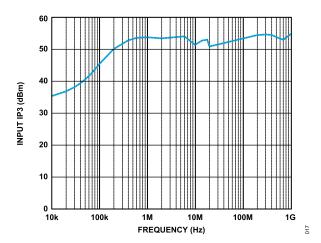


Figure 17. Input IP3 vs. Frequency, Low Frequency Detail

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#### THEORY OF OPERATION

The ADRF5023 integrates a driver to perform logic function internally and to provide the advantage of a simplified control interface. The driver features two digital control input pins (CTRL and EN) that control the state of RF paths, determining which RF port is in insertion loss state and which RF port is in isolation state (see Table 7).

#### **POWER SUPPLY**

The ADRF5023 requires a positive supply voltage applied to the  $V_{DD}$  pin and a negative supply voltage applied to the  $V_{SS}$  pin. Bypassing capacitors are recommended on the supply lines to minimize RF coupling.

The ideal power-up sequence is as follows:

- 1. Connect the ground.
- 2. Power up  $V_{DD}$  and  $V_{SS}$ . Power up  $V_{SS}$  after  $V_{DD}$  to avoid current transients on  $V_{DD}$  during ramp-up.
- 3. Power up the digital control inputs. Power the digital control inputs before the  $V_{DD}$  supply can inadvertently forward bias and damage the internal ESD protection structures. To avoid this damage, use a series 1 k $\Omega$  resistor to limit the current flowing into the control pin. Use pull-up or pull-down resistors if the controller output is in a high-impedance state after  $V_{DD}$  is powered up and the control pins are not driven to a valid logic state.
- 4. Apply an RF input signal.
- The ideal power-down sequence is the reverse order of the power-up sequence.

### **Single-Supply Operation**

The ADRF5023 can operate with a single positive supply voltage applied to the  $V_{DD}$  pin and  $V_{SS}$  pin connected to ground. However, some performance difference can occur in switching characteristics and large signal, see Table 1 for more details.

### **RF INPUT AND OUTPUT**

All of the RF ports (RFC, RF1, RF2) are DC-coupled to 0 V, and no DC blocking is required at the RF ports when the RF line potential is equal to 0 V.

The RF ports are internally matched to 50  $\Omega$ . Therefore, external matching networks are not required.

When the EN pin is logic low, the logic level applied to the CTRL pin determines which RF port is in insertion loss state and which RF port is in isolation state. The insertion loss path conducts the RF signal between the selected RF throw port and the RF common port. The isolation path provides high loss between the insertion loss path and the unselected RF throw port that is terminated to an internal 50  $\Omega$  resistor.

When the EN pin is logic high, the switch is in an all-off state regardless of the logic state of the CTRL pin. Both the RF1 to RFC path and the RF2 to RFC path are in an isolation state. The RF1 and RF2 ports are terminated to internal 50  $\Omega$  resistors, and the RFC port becomes reflective open.

The switch design is bidirectional with equal power handling capabilities. The RF input signal can be applied to the RFC port or the selected RF throw port.

Table 7. Control Voltage Truth Table

|      | Digital Control Inputs RF Paths |                     | Paths               |
|------|---------------------------------|---------------------|---------------------|
| EN   | CTRL                            | RF1 to RFC          | RF2 to RFC          |
| Low  | Low                             | Isolation (off)     | Insertion loss (on) |
| Low  | High                            | Insertion loss (on) | Isolation (off)     |
| High | Low                             | Isolation (off)     | Isolation (off)     |
| High | High                            | Isolation (off)     | Isolation (off)     |

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#### **APPLICATIONS INFORMATION**

The ADRF5023 has two power supply pins ( $V_{DD}$  and  $V_{SS}$ ) and two control pins (CTRL and EN). Figure 18 shows the external components and connections for supply and control pins. The  $V_{DD}$  pin and the  $V_{SS}$  pin are decoupled with a 100pF multilayer ceramic capacitor. The device pin-out allows the placement of the decoupling capacitors close to the device. No other external components are needed for bias and operation, except DC blocking capacitors on the RF pins when the RF lines are biased at a voltage different than 0 V. For more details, see the Pin Configuration and Function Descriptionssection.

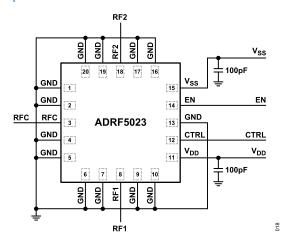


Figure 18. Recommended Schematic

### RECOMMENDATIONS FOR PCB DESIGN

The RF ports are matched to  $50~\Omega$  internally, and the pin out is designed to mate a coplanar waveguide (CPWG) with a  $50~\Omega$  characteristic impedance on the PCB. Figure 19 shows the referenced CPWG RF trace design for an RF substrate with 8 mil thick Rogers RO4003 dielectric material. RF trace with 14 mil width and 7 mil clearance is recommended for 1.5 mil finished copper thickness.

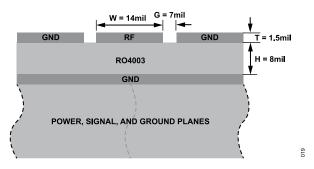


Figure 19. Example PCB Stack Up

Figure 20 shows the routing of the RF traces, supply, and control signals from the device. The ground planes are connected with as many filled, through vias as allowed for optimal RF, and thermal performance. The primary thermal path for the device is the bottom side.

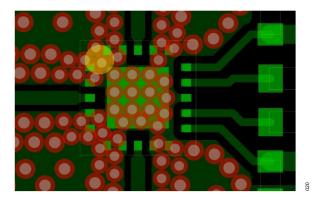


Figure 20. PCB Routings

Figure 21 shows the recommended layout from the device RF pins to the  $50~\Omega$  CPWG on the referenced stack-up. PCB pads are drawn 1:1 to device pads. The ground pads are drawn soldermask defined and the signal pads are drawn as pad defined. The RF trace from the PCB pad is extended with the same width till the package edge and tapered to the RF trace with a  $45^{\circ}$  angle. The paste mask is also designed to match the pad without any aperture reduction and is divided into multiple openings for the paddle.

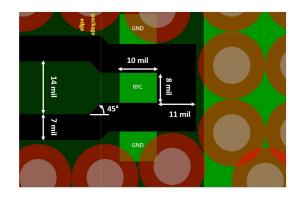


Figure 21. Recommended RF Pin Transitions

For alternate PCB stack-ups with different dielectric thickness and CPWG design, contact Technical Support for further recommendations.

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#### **OUTLINE DIMENSIONS**

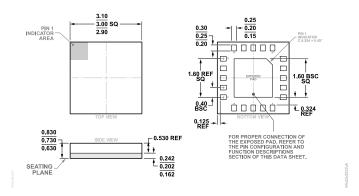


Figure 22. 20-Terminal Land Grid Array [LGA]
3.0 mm × 3.0 mm Body and 0.730 mm Package Height
(CC-20-19)
Dimensions shown in millimeters

Updated: August 11, 2023

## **ORDERING GUIDE**

| Model <sup>1</sup> | Temperature Range | Package Description               | Packing Quantity | Package<br>Option | Marking Code |
|--------------------|-------------------|-----------------------------------|------------------|-------------------|--------------|
| ADRF5023BCCZN      | -40°C to +105°C   | 20-Terminal Land Grid Array (LGA) | Reel, 500        | CC-20-19          | 023          |
| ADRF5023BCCZN-R7   | -40°C to +105°C   | 20-Terminal Land Grid Array (LGA) | Reel, 1500       | CC-20-19          | 023          |

<sup>&</sup>lt;sup>1</sup> Z = RoHS Compliant Part.

## **EVALUATION BOARDS**

Table 8. Evaluation Boards

| Model <sup>1</sup> | Description      |
|--------------------|------------------|
| ADRF5023-EVALZ     | Evaluation Board |

<sup>&</sup>lt;sup>1</sup> Z = RoHS-Compliant Part.

